

Isc N-Channel MOSFET Transistor

SUP70040E

• FEATURES

- TrenchFET® Power MOSFET
- 175 ° C Junction Temperature
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

• APPLICATION

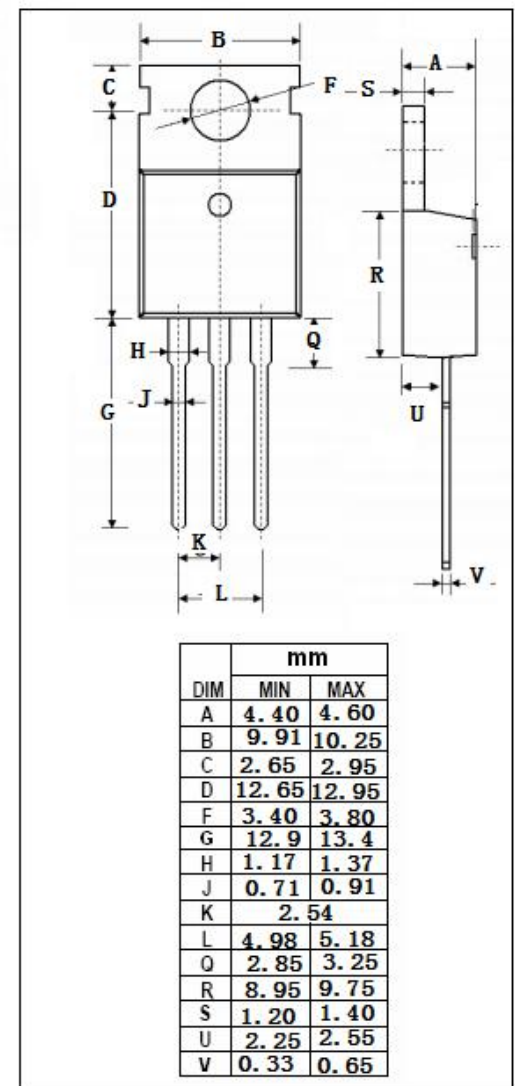
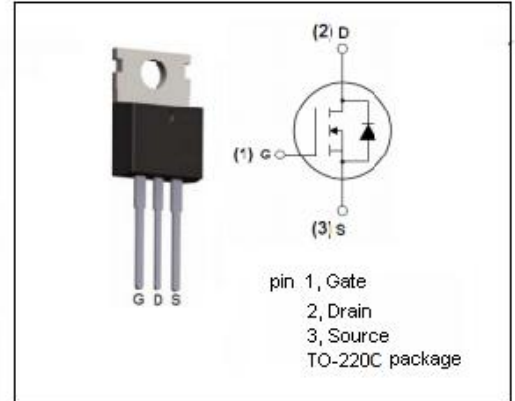
- Power Supply
 - Secondary Synchronous Rectification
- Power tools
- Motor drive switch
- Battery management

• ABSOLUTE MAXIMUM RATINGS(T_a=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage	100	V
V _{GSS}	Gate-Source Voltage	±20	V
I _D	Drain Current-Continuous@T _c =25°C (T _j =150°C)	120	A
	T _c =70°C	120	
I _{DM}	Drain Current-Single Pulsed(t=100 μ s)	480	A
P _D	Total Dissipation @T _c =25°C	375	W
	T _c =125°C	125	
T _{ch}	Max. Operating Junction Temperature	-55~175	°C
T _{stg}	Storage Temperature	-55~175	°C

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R _{th(ch-c)}	Channel-to-case thermal resistance	0.4	°C/W
R _{th(ch-a)}	Channel-to-ambient thermal resistance	40	°C/W



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ELECTRICAL CHARACTERISTICS

 T_C=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 0.25mA	100			V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = ±20V; I _D =0.25mA	2.5		4.0	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D =20A V _{GS} = 7.5V; I _D =15A			4.0 4.6	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±20V; V _{DS} = 0V			±0.25	μA
I _{DSS}	Drain-Source Leakage Current	V _{DS} = 100V; V _{GS} = 0V; T _J =25°C T _J =125°C T _J =150°C			1 150 5000	μA
V _{SDF}	Diode forward voltage	I _F =10A, V _{GS} = 0 V			1.5	V

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